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Cl alloying improves thermal stability and increases luminescence in iodine-rich inorganic perovskites†

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The inorganic perovskite CsPbI₃ shows promising photophysical properties for a range of potential optoelectronic applications but is metastable at room temperature. To address this, Br can be alloyed into the X-site to create compositions such as CsPbI₂Br that are stable at room temperature but have bandgaps >1.9 eV – severely limiting solar applications. Herein, in an effort to achieve phase stable films with bandgaps <1.85 eV, we investigate alloying chlorine into iodine-rich triple-halide CsPb(I_{0.8}Br_{0.2-x}Cl_x)₃ with 0 < x < 0.1. We show that partial substitution of iodine with bromine and chlorine provides a path to maintain broadband terrestrial absorption while improving upon the perovskite phase stability due to chlorine's smaller size and larger ionization potential than bromine. At moderate Cl loading up to ≈5%, X-ray diffraction reveals an increasingly smaller orthorhombic unit cell, suggesting chlorine incorporation into the lattice. Most notably, this Cl incorporation is accompanied by a significant enhancement over Cl-free controls in the duration of black-phase stability of up to 7× at elevated temperatures. Additionally, we observe up to 5× increased steady state photoluminescence intensity (PL), along with a small blue-shift. In contrast, at high loading (≈10%), Cl accumulates in a second phase that is visible at grain boundaries via synchrotron fluorescence microscopy and negatively impacts the perovskite phase stability. Thus, replacing small fractions of bromine for chlorine in the iodine-rich inorganic perovskite lattice results in distinct improvement thermal stability and optoelectronic quality while minimally impacting the bandgap.

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1 Introduction

Metal halide perovskites of the form ABX₃ exhibit excellent light absorption,¹ long carrier-diffusion lengths,² and – critically – a tunable electronic bandgap.^{3,4} These properties have made them a promising class of materials for light emitting diodes,⁵ photodetectors,⁶ and photovoltaics.^{7–12} However, their predominately I-rich organic-inorganic compositions suffer from phase instability, thermal instability, water-mediated decomposition, deleterious condensation reactions, and light-induced degradation that drastically limits their stability and thus application.^{13–15}

To improve upon phase stability, which can be understood heuristically through the Goldschmidt tolerance factor, the

community has often alloyed smaller halides, such as Br, at the X-site.^{16,17} While alloying with Br is a viable approach to increase phase stability,¹⁸ too large a fraction of Br in organic-inorganic APb(I_{1-x}Br_x)₃ has been shown to cause halide segregation under non-equilibrium conditions of light or potential bias.^{14,19,20} In contrast, alloying with Cl has been shown to improve phase stability without inducing light- or bias-driven segregation.²¹ Moreover, addition of Cl into organic-inorganic perovskites has been shown to reduce device voltage losses.¹⁰

However, the amount of Cl remaining in the final film depends greatly on the loading level, annealing condition, and cation composition – which can provide a reaction pathway for Cl to leave during crystallization. For example, when Cl is introduced in the presence of methylammonium (MA) or formamidinium (FA), MAcl or FAcI has been shown to volatilize to some degree during perovskite crystallization.²² Specifically, FAcI has been shown to undergo weight loss at 161 °C via differential scanning calorimetry (DSC) and a phase change at 191 °C via thermogravimetric analysis (TGA).²³ Even when the fraction of Cl that volatilizes is significant, Cl one-step addition^{24,25} and two-step addition²⁶ to precursor inks has still been found to enhance grain growth,^{27,28} and increase

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luminescence,²⁹ without substantially modifying the final material composition or bandgap.^{22,30–32} In contrast, when Cl lacks sufficient avenues for volatilization, it has been shown to both incorporate into the lattice and increase elemental heterogeneity, as indicated by diffraction¹⁰ and nano X-ray fluorescence (nXRF)³³ respectively.

A-site alloys, now often FA-based system with small amounts of Cs and MA to modulate crystallization and improve phase stability, still suffer from many of the same chemical degradation mechanisms, albeit at slower rates. For example, Tan *et al.*, showed that triple cation systems employing Cs, MA, and FA thermally degrade at two distinct rates, one associated with the volatilization of MA and one with the volatilization of FA.³⁴ Consequentially, going fully inorganic at the A-site offers a distinct approach to addressing the issue of perovskite durability; by removing the A-site organic components, inorganic perovskites are no longer susceptible to the various condensation reactions³⁵ or thermal degradation³⁴ that has been shown occur in the mixed organic systems. All-inorganic perovskite systems have the strongest reported operational stability (equivalent to ≥ 5 years at 35 °C)³⁶ and improved elevated stability under light and heat.^{37,38} Nevertheless, halide perovskites need to improve their operational durability on the order of a magnitude before they can become commercially viable.³⁹

While all-inorganic perovskite systems avoid some of the chemical stability challenges intrinsic to their hybrid counterpart, all-inorganic systems, like CsPbI₃, suffer from thermodynamic phase instability near room temperature. CsPbI₃ can take on three photoactive perovskite phases (α -cubic, β -tetragonal, γ -orthorhombic) that are metastable to transformation to the non-photoactive non-perovskite phase (δ -orthorhombic) at room temperature.^{40,41} This instability is further exacerbated in ambient conditions as humidity catalyzes the γ -CsPbI₃ to δ -CsPbI₃ transition.⁴² To improve phase stability, the community has taken an analogous approach to the organic–inorganic systems by alloying smaller halides into the lattice. For example, Nasstrom *et al.* have shown that substituting I with Br to form CsPbI₂Br delivers photo-active phase stability above ≈ 300 K.³⁷

In these high Br fraction CsPbI₂Br alloys, Cl alloying has been studied as a strategy toward further improvement of grain growth and black-phase stability in ambient conditions.^{43–47} However, the large Br site fraction in CsPbI₂Br increases the bandgap to >1.9 eV, limiting terrestrial solar light absorption.^{45,48} Cl alloying has been found to enhance the steady state photoluminescence over Cl-free controls by up to $\approx 1.4\times$ in all-inorganic^{12,40,49,50} and $\approx 4.2\times$ in organic containing^{24,28,51–62} systems.

The need to enhance performance and maintain silicon-tandem relevant bandgaps without largely affecting bandgap motivates alloying Cl into higher I fraction inorganic compositions. Triple halide alloying at ≤ 1.85 eV bandgap in all-inorganic compositions has been only studied in very limited fashion to date but have shown some promise to enhance photovoltages.⁶³ These compositions show promising enhancement to photovoltaic device voltages. However, the thermal stability of such triple halide inorganic phases is unknown.

Here, we investigate previously unexplored regimes of Cl loading in triple-halide inorganic alloys and identify triple-halide compositions of improved thermal stability and optoelectronic properties, focusing on full-spectrum visible-light absorbing ≈ 1.83 eV CsPb(I_{0.80}Br_{0.20–x}Cl_x)₃ films. Using a combination of diffraction, optical spectroscopy, and micro-spectroscopy, we show that Cl incorporation up until $\approx 5\%$ Cl. With 5% Cl incorporation, we measure $5\times$ enhanced steady state photoluminescence (PL) and $7\times$ increased duration of black-phase stability at elevated temperatures (≥ 60 °C) over Cl-free controls. At $\approx 10\%$ Cl, we observe evidence of secondary phases that negatively affect the stability of the film. Our observations show that modest Cl substitution in triple-halide inorganics can increase PL intensity and thermal stability without significant modification to bandgap, enabling material enhancement for broadband solar absorption.

2 Experimental

2.1 Materials

All materials were purchased from Sigma-Aldrich with specifications detailed in Table S1† and used without further purification.

2.2 Fabrication: substrate preparation

TEC 8 ITO substrates (Biotain), float-glass (Thermo Fisher Scientific), and quartz (Chemglass) substrates were sonicated sequentially in a 2% detergent (Hellmanex-III) deionized water mix, deionized water, acetone, and isopropanol alcohol for 15 min each. At the end of the isopropanol sonication, substrates were removed one at a time and dried immediately with a filtered N₂ stream to prevent organic residue on the surface of the films. Prior to deposition, substrates were cleaned by UV-ozone for 15 min with an O₂ flow rate of 500 cc per min.

2.3 Fabrication: perovskite

All-inorganic perovskite thin films with nominal stoichiometries of CsPb(I_{0.80}Br_{0.20–x}Cl_x)₃ ($x = 0.10, 0.05, 0.01, 0$) were targeted using a formamidinium acetate (FAAc) templating strategy⁶⁴ and excess lead iodide. Specifically, FAc, CsI, PbI₂, PbBr₂, and PbCl₂ precursor powders were mixed in appropriate ratios to obtain the compositions listed above for each Cl loading. Next, 25% mole fraction FAc relative to A-site was added to each vial, which has been reported to template the high symmetry cubic phase at low temperature, and then volatilize off and exchange with Cs at high temperature to create a fully inorganic film.⁶⁴ Finally, 12% excess of PbI₂ was added to each vial in an attempt to ensure that film surfaces and domain boundaries were passivated.⁶⁵ The precursor powders were then dissolved in DMSO at 1.33 M with respect to Cs using a vortex mixer. Prior to deposition, the solution was filtered into another vial using a 200 nm pore size PTFE membrane, and then dispensed onto substrates which were then spun at 500 rpm for 10 s and then at 3250 rpm for 50 s. At 5 s remaining in the second cycle, 200 μ L of methyl-acetate (MeOAc) was dispensed in a continuous and uniform stream *via* a 1000 μ L pipette; MeOAc was chosen due to



its superior ability to decomplex Cs from DMSO.⁶⁶ Wet films were left to dry in inert 25 °C conditions for 1 h and then annealed at 230 °C for 10 min, resulting in approximately 550 nm thick films (Fig. S1†). Hot plates used had temperature precision of <5%. All film preparation was performed in an inert nitrogen glovebox at <1 ppm water and oxygen.⁶⁴

2.4 Characterization: benchtop X-ray diffraction (XRD)

XRD measurements were taken with a Rigaku SmartLab diffractometer using an 8.04 keV Cu K α parallel beam light source with a K β filter. Float-glass/perovskite samples were coated with several μ m of polyisobutylene rubber (PIB) (70 mg mL⁻¹ in chlorobenzene) with no additives as a barrier layer to prevent moisture-induced degradation (Fig. S1†). DICVOL14 (ref. 67) software was used to index diffraction peaks according to an orthorhombic *Pnma* space group; lattice constants and satisfactory de Wolff figures of merit (≥ 10) were obtained, as shown in Table S2.†,†⁶⁸ Tabulated lattice volumes can be found in Table S2.†

2.5 Characterization: scanning electron microscopy (SEM)

SEM measurements were performed using a Thermo Fisher Apreo microscope, equipped with an in-lens backscattered electron detector. Images were scaled using real space pixel area value to match field of view area across all samples. Apparent grain domain size analysis was then conducted by summing pixels within a manually drawn convex hull in ImageJ, with apparent area calculated *via* the set pixel to real space scale.

2.6 Characterization: synchrotron X-ray fluorescence spectroscopy

Synchrotron-based nanoprobe X-ray fluorescence (nXRF) measurements were taken using both a 270 nm full-width half-maximum (FWHM) focused beam at 7 keV and a 380 nm FWHM focused beam at 16.4 keV at beamline 2-IDD of the Advanced Photon Source (APS) at Argonne National Laboratory (ANL) in a helium environment. The lower 7 keV beam energy was employed to enable sensitivity to Cl. Mapping regions were aligned between the two measurement energies *via* gold fiducials, and maps generated by the smaller probe were blurred to match the larger probe size using a Gaussian kernel and then averaged.⁶⁹ Similar to previous investigations,³³ the nXRF measurement was conducted through the backside of a gold contact, with a full fluorescence spectrum collected point-by-point for each location on the map. Cl in soda lime glass substrate, which has a common range of 0.5–3 wt% Cl,⁷⁰ was subtracted as background. For domain boundary analysis, nXRF measurements were taken utilizing a 30 nm FWHM focused beam at 8.5 keV at beamline 26-IDC of the APS at ANL in a vacuum environment. For all nXRF analysis, MAPS software was used to fit the background and perform peak deconvolution.^{33,71,72} A list of similar synchrotron light sources and their relevant capabilities toward characterization of perovskite can be found in a review by Kodur *et al.*⁷³

2.7 Characterization: ultraviolet-visible (UV-vis) absorption spectroscopy

UV-vis absorption spectroscopy measurements of thin films were taken using an integrating sphere setup (PerkinElmer Lambda 1050). Following transmission and reflection measurements, absorption was calculated and direct transition Tauc plots were fit to estimate the optical bandgap of the absorber. For all UV-vis absorption spectroscopy measurements, float-glass/perovskite samples were encapsulated in glass as previously described. A total of 5 samples were measured for each condition (Fig. S2†), with the median sample shown in Fig. 3.

2.8 Characterization: photoluminescence spectroscopy (PL)

PL measurements were taken with a Raman microscope (Renishaw inVia). For large-area sampling and single point spectra, a 633 nm laser was operated at 1.75 mW with a 6 μ m spot size and a 600 mm⁻¹ grating. Sampling was done on a 300 \times 300 μ m area with a point to point spacing of 10 μ m. For μ PL mapping measurements, a 532 nm laser was operated at 200 mW with a 865 nm spot size and a 1800 mm⁻¹ grating. For all PL measurements, float-glass/perovskite samples were encapsulated between two sheets of glass using PIB (Quanex) edge seal pressed at 70 °C and 20 psi to prevent moisture-induced degradation.⁷⁴ Raw spectra, shown in Fig. S3,† were smoothed *via* a 0.015 eV moving average Savitzky–Golay filter⁷⁵ to remove interference effects of the glass encapsulating layer. Time series of peak PL emission energy and PL FWHM data was smoothed using a 100 s rolling average filter.

2.9 Characterization: fourier transform infrared spectroscopy attenuated total reflectance (FTIR-ATR)

FTIR-ATR (PerkinElmer UATR Two) was carried out on thin films before their anneal and shortly after their anneal to record any loss in organic material. Background scans were taken between diamond ATR crystal and the probe head subsequent to each sample scan.

2.10 Characterization: photoluminescence quantum yield (PLQY)

Photoluminescence quantum yield (PLQY) measurements were carried out on a homebuilt setup consisting of a 532 nm DPSS laser module controlled by a laser diode controller (SRS, Model LDC502) coupled into an integrating sphere (Newport, Model 819C-SF-4). The sphere was fitted with a switchable-gain Si photodetector (Thorlabs PDA100A2) with an automated filter slider (Thorlabs, ELLK6) loaded with a 600 nm longpass filter (Thorlabs FELH600, O.D. 6). To increase signal-to-noise ratio, the laser was modulated at 993 Hz about a 1-sun equivalent injection and photodetector signal was read out using a lock-in amplifier (SRS, Model SR830). PLQY was calculated using the method developed by de Mello *et al.*,⁷⁶ with the responsivity of the Si photodetector accounted for using a photoluminescence spectrum of each sample and the responsivity of the detector.



To calculate the quasi-Fermi level splitting, the following relationship was used, adapted from de Mello *et al.*:⁷⁶

$$QFLS = V_{lim} + kT \ln(PLQY) \quad (1)$$

where V_{lim} is the detailed balance limited voltage at 1-sun and kT is the thermal voltage at room temperature. The detailed balance limit voltage was calculated using the optical bandgap acquired through Tauc plot analysis of the UV-vis data.

2.11 Characterization: thermal stability

Within 24 hours of formation at 230 °C, films of each composition were brought from room temperature to 60 °C, 85 °C, and 100 °C to probe the kinetics of phase transformation using the visual yellowing of the film as an indicator for the phase transformation from one of the photoactive black phases to the non-perovskite yellow δ -phase. Measurements were conducted in a glovebox with ≤ 1 ppm oxygen and moisture. Videos of the degrading films were taken utilizing a camera (GoPro) recording at 6 frames per minute. To process the data, the center 2 cm of each 2.5 cm substrate were averaged and converted to grayscale. Then, initial intensities within each Cl loading were normalized to account for nonuniform lighting in the glovebox. Variations in light intensity caused by variable ambient light in the laboratory were filtered out and the temporally-adjacent points were used to linearly interpolate across the filtered time points. Finally, the onset of discoloration was determined by fitting the linear portion of the discoloration curve and using the x -axis intercept as the onset value. For samples where the onset of discoloration was not observed, the total duration of the test was used as a conservative estimate for the onset value. Raw time lapse videos can be found in the ESI.†

3 Results and discussion

Inorganic $\text{CsPb}(\text{I}_{0.80}\text{Br}_{0.20-x}\text{Cl}_x)_3$ films with $x = 0$ to 0.10 were investigated for their composition uniformity, optoelectronic quality, and phase stability especially at elevated temperatures and are hereafter referred to as 0% Cl, 1% Cl, 5% Cl, and 10% Cl. To better understand the effect of adding Cl into the solution and its resultant effect on the final film, a series of analysis techniques were performed, including X-ray diffraction (XRD), scanning electron microscopy (SEM), synchrotron-based nano-X-ray fluorescence (nXRF), photoluminescence (PL), and thermal degradation tests.

Analysis of XRD patterns reveals incorporation of Cl into the lattice until 5% Cl, followed by phase segregation and the emergence of a secondary Br- or/and Cl-rich phase (Fig. 1a). Extracted orthorhombic ($Pnma$) lattice volumes as a function of Cl loading are shown in Fig. 1b. As can be seen in Fig. 1b, the lattice volume shrinks up to 5% Cl, followed by a lattice expansion at 10% Cl. To estimate the lattice volume, the full XRD patterns (Fig. 1a) were indexed using DICVOL14. Due to the texture of the thin films, discriminating the space group of the black phase is a challenge. The minor peaks appearing between $23^\circ 2\theta$ and $25^\circ 2\theta$ in the patterns (Fig. 1a) are consistent with the literature suggesting the $Pnma$ γ - CsPbI_3 phase is

favoured at room temperature.⁷⁷ Williamson–Hall analysis of the diffraction patterns revealed relaxation of strain with increasing Cl loading (Fig. S4†). No measurable strain was present at 5 or 10% Cl compared to a strain of 5×10^{-3} in Cl free controls. No evidence of a non-perovskite δ -phase was found in any samples, *e.g.*, indicated by the lack of a peak at $\approx 10^\circ 2\theta$ in Fig. 1a. However, a secondary peak emerges at 10% Cl at slightly larger 2θ relative to the main $\{002\}$ peak. The emergence of a secondary peak at smaller d-spacing and the main phase's larger lattice volume at 10% Cl suggests that the main phase becomes more I-rich while a Cl- and Br-rich secondary phase emerges. This trend in the inorganic triple halide perovskite is analogous to the lattice volume behavior upon Cl incorporation reported by Xu *et al.* in recent work on triple halide organic–inorganic perovskites, who ascribed the observed trends to a solubility limit for Cl within the lattice.¹⁰ In short, it appears that up until 5% Cl, Cl successfully incorporates into the lattice, causing a decrease in lattice volume with no additional peaks/phases. Beyond 10% Cl, we expect continued evidence of secondary phases.

SEM results show that at low loading Cl changes film morphology relatively little, while at 10% Cl loading it increases the nucleation density as seen in Fig. 2a–d (full area SEM images in S5†). At 10% Cl, pinholes are eliminated and there is a reduction of median apparent grain domain size (Fig. S6†). Given that this change in morphology at 10% Cl appears to correlate well to the emergence of a secondary peak in XRD, we believed that many of these additional nucleation points may be from Cl-rich phases.

nXRF identifies three distinct Cl loading regimes. As can be seen in Table 1 the average Cl fraction measured in each film correlates well to its loading concentration, but is consistently lower. This reduction in Cl fraction of the final film indicates the likely volatilization of at least a fraction of FACl during the 230 °C anneal. FACl is known to undergo mass loss at 161 °C.²³ The XRF maps used to tabulate the average values in Table 1 are shown in Fig. S7.† Additionally, we conducted FTIR-ATR (Fig. S8†) and observed the disappearance of characteristic vibrations at $\approx 3400 \text{ cm}^{-1}$ and $\approx 1400\text{--}1500 \text{ cm}^{-1}$ after the 230 °C anneal.⁷⁸ The relatively similar Cl concentrations in the 0% and 1% Cl-loaded films may suggest that much of the Cl volatilizes away at low loading. This is consistent with reports in organic systems.^{79,80} It thus appears Cl loading has three distinct regimes: (1) at low Cl loading, most Cl volatilizes off, (2) at moderate Cl loading less than the solubility limit of Cl within the lattice, some Cl volatilizes off and some incorporates into the lattice as indicated by a smaller unit cell in XRD, and (3) at high Cl loading that exceeds the solubility limit of Cl within the lattice, some Cl volatilizes off, a fraction incorporates in to the main phase, but most nucleates out into a Cl-rich phase as evidenced by XRD.

To better understand how the three distinct regimes of Cl incorporation affect the optoelectronic properties of the films, UV-vis absorption, μPL , and PL quantum yield (PLQY) measurements were performed. The optical Tauc bandgap shows only a small $\approx 3 \text{ meV}$ blue-shift when adding 5% Cl and a $\approx 17 \text{ meV}$ red-shift at 10% Cl relative to the control, as seen in



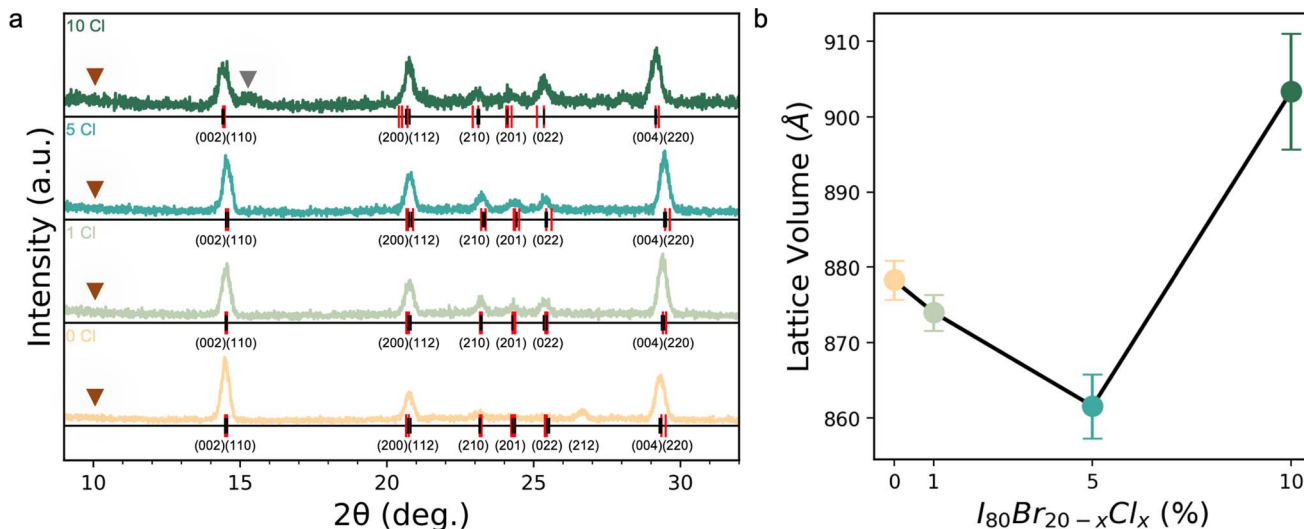


Fig. 1 (a) Parallel beam thin film diffraction XRD of CsPb(I_{0.80}Br_{0.20-x}Cl_x)₃ films with Cl varied from 0% to 10%. The orthorhombic (*Pnma*) calculated peaks are marked as red vertical lines, with observed two theta peak location as black vertical lines. Emerging secondary phase in 10% Cl marked with gray arrow and the location of the non-perovskite δ -phase peak were it to be present marked by the brown triangle. 8.04 keV X-ray source. (b) Lattice volume calculated from DICVOL14 based on orthorhombic indexing.

Fig. 3a. 1% Cl addition appears to lead to minimal changes in absorption onset. These trends are consistent in measurements of 5 samples at each loading, though the variation in the absorption onset increases with Cl loading (Tauc analysis in Fig. S2† and UV-vis spectra in Fig. S9†), which suggests increasing heterogeneity. Cl has been previously shown to incorporate heterogeneously in hybrid halide perovskite alloy thin films,³³ and, similarly, heterogeneity appears to increase with increasing Cl content in the all-inorganic halide alloy.

Fig. 3b shows that a monotonic increase in PL intensity is seen with Cl addition but the energy of the peak emission first blue shifts a small amount up to 5% Cl, then at 10% Cl reverts to near the 0% Cl maximum. At 1% Cl, the PL emission energy is nearly identical but slightly blue-shifted from the control, consistent with limited Cl incorporation to the crystal structure. At 5% Cl, Cl incorporation into the lattice results in a 12.5 meV PL blue-shift in emission energy as well as increased intensity. Notably, at 5% Cl there is a larger increase in the PL emission

energy (≈ 10 meV) than the shift in the optical bandgap (≈ 3 meV), corroborating an improvement in optoelectronic quality. At 10% Cl, the PL emission red-shifts, broadens, increases intensity, and becomes asymmetric, which is consistent with Cl leading to the precipitation of phases with varied halide content and therefore varied emission profiles. The red-shift with respect to the control seen in 10% Cl films is expected as the minor phase at smaller d-spacing likely contains Br, leading to the main phase becoming relatively richer in I.

To further quantify luminescence, we conducted PLQY (Fig. 3c) and observed supporting evidence of increased luminescence with Cl loading. PLQY values on the order of 0.01% indicate substantial non-radiative losses in the films, and are similar to the more commonly investigated all inorganic ≈ 1.7 eV CsPbI₃ (ref. 81) (PLQY of $\approx 0.04\%$) yet less luminescent than hybrid ≈ 1.55 eV bandgap Cs_{0.05}(FA_xMA_y)_{0.95}Pb(I_xBr_y)₃ (ref. 82) (PLQY of $\approx 3\%$). But, across all Cl concentrations, PL intensity and PLQY increases with Cl loading. The

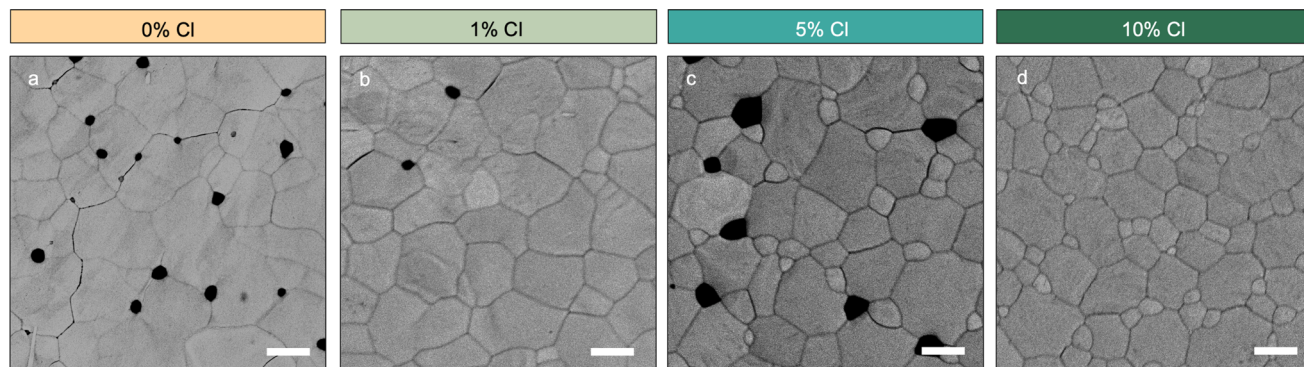


Fig. 2 (a–d) SEM images of CsPb(I_{0.80}Br_{0.20-x}Cl_x)₃ with Cl varied from 0% to 10% showing increasing apparent domain size until 1% followed by a decrease in size. Scale bar 2 μ m.

Table 1 Average measured molar halide fraction from the 10 μm area nXRF measurements of each Cl loading ($\text{CsPb}(\text{I}_{0.80}\text{Br}_{0.20-x}\text{Cl}_x)_3$) and nominal precursor solution amounts, including 12% excess PbI_2

Cl%	Nominal I%	Measured I%	Nominal Br%	Measured Br%	Nominal Cl%	Measured Cl% above background
0	81	84.2	19	15.9	0	0
1	80.8	82.9	18.3	17.2	0.9	0.02
5	81.3	84.1	14.1	14.0	4.5	1.98
10	80.8	81.0	9.6	13.3	9.6	5.72

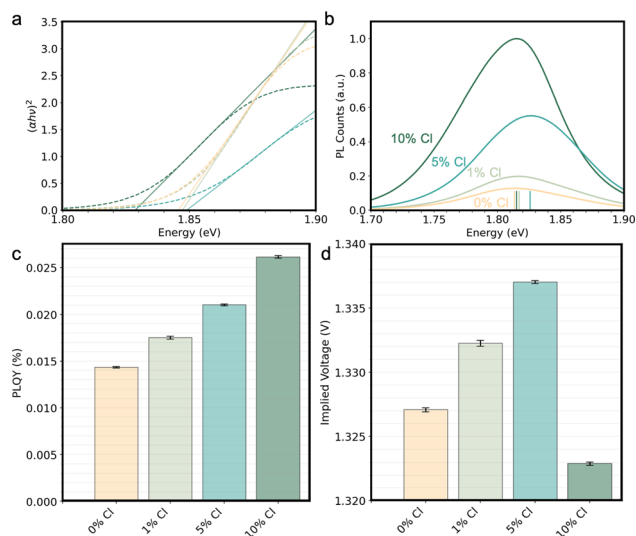


Fig. 3 (a) Direct transition Tauc plots of $\text{CsPb}(\text{I}_{0.80}\text{Br}_{0.20-x}\text{Cl}_x)_3$ with Cl varied from 0% to 10% generated with best fit line drawn to the intercept. (b) PL spectra with vertical line denoting peak PL energy. (c) PLQY bar plots of films. (d) Calculated implied voltage of films using median bandgap from Tauc plot.

corresponding implied voltage under 1-sun illumination is shown in (Fig. 3d), where due to the bandgap narrowing at 10% Cl, the implied voltage (eqn (1)) is greatest at 5% Cl amongst all conditions. Without evidence of secondary phases nor an increased in apparent domain size in the $\leq 5\%$ Cl films, the increasing PLQY may be due to the increased passivation of Shockley–Read–Hall recombination centers similar to its effects in MAPbI_3 .²⁵ Collectively, these results suggest that increasing the Cl loading increases quasi-Fermi level splitting, at least in the intensely light-emitting regions of the film, which become heterogeneously distributed in the 10% Cl films as described below.

Microscopic μPL and nXRF mapping on the 10% Cl sample reveals a distribution of Cl at apparent domain boundaries that appears to correlate well with PL intensity and emission energy. μPL maps as a function of intensity and emission energy are shown in Fig. 4a and b, while nXRF maps of the total fluorescence yield and Cl to I ratio are shown in Fig. 4c and d, respectively. As can be seen in the PL maps, there are substantial spatial variations in the PL intensity and peak emission energy, explaining the shoulders in the area-averaged PL emission spectra above. Moreover, the PL intensity appears

to be maximal in regions where the emission energy changes most drastically (likely due to varied halide content) and at the edge of the apparent domains (e.g. Area 1 in Fig. 4a). nXRF shows reduced total fluorescence yield and a large concentration of Cl with respect to I at such domain boundaries. DeQuilettes *et al.* previously demonstrated a correlation between local Cl content in the film and PL intensity in MAPbI_3 .²⁹ Moreover, the increase in PL intensity of the 10% Cl samples is analogous to the results in organic-inorganic perovskites of Frohna *et al.*, who found evidence for a similar carrier funneling mechanism from Br-rich to I-rich areas in $\text{FA}_{0.79}\text{MA}_{0.16}\text{Cs}_{0.05}\text{Pb}(\text{I}_{0.83}\text{Br}_{0.17})_3$.⁸³ Together, the trends in the inorganic triple halide films are consistent with carrier funneling from a Cl-rich wider bandgap material at the domain boundaries to I-rich narrower material within the domains.

To investigate the stability of these phases over time, prolonged PL measurements were conducted, which revealed that the peak emission energy and FWHM was relatively robust to illumination across 0% Cl through 5% Cl conditions (Fig. 5a and b). Conversely in 10% Cl, we observed a minor peak PL energy red-shift and FWHM broadening over the duration of the test. Full PL spectra over time are shown on edge-sealed glass

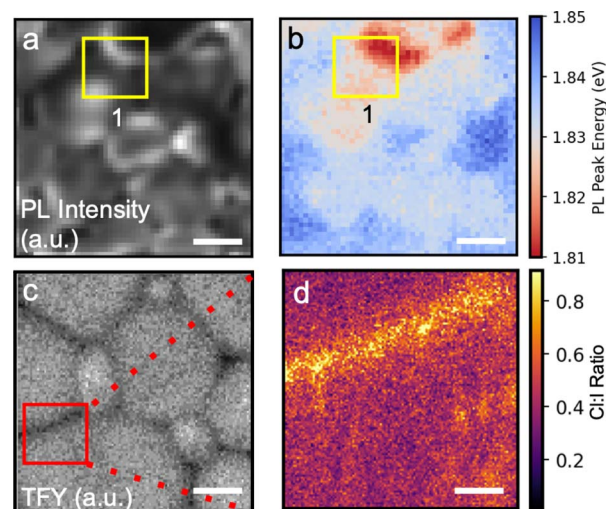


Fig. 4 (a) μPL maps of $\text{CsPb}(\text{I}_{0.80}\text{Br}_{0.10}\text{Cl}_{0.10})_3$ showing contrast (1) of PL intensity with (b) spatially heterogeneous peak PL emission energy (scale bar 4 μm). (c) Corresponding nXRF total fluorescence yield (TFY) with 10 μm FoV showing clear apparent boundary regions (scale bar 2 μm) with (d) zoom (3 μm FoV) showing a high ratio of Cl to I at the boundary (scale bar 600 nm).



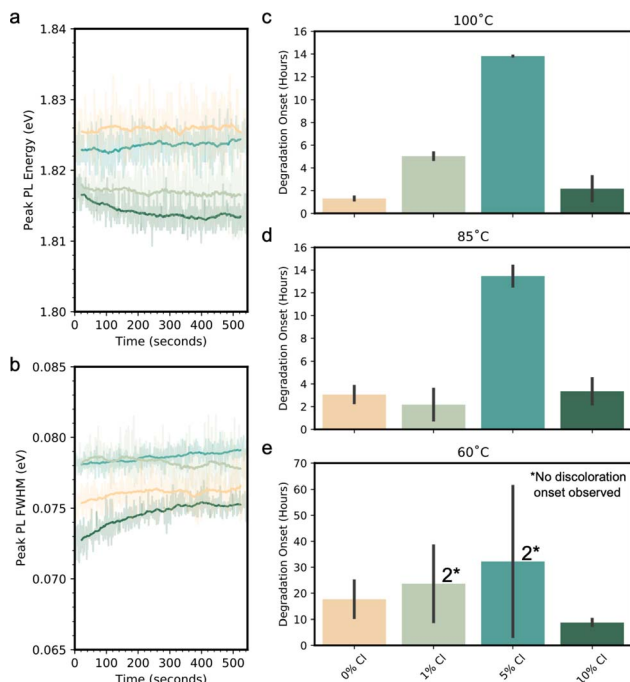


Fig. 5 (a) Peak PL emission energy and PL FWHM (b) of $\text{CsPb}(\text{I}_{0.80-\text{Br}_{0.20-x}\text{Cl}_x})_3$ films collected from a single point (6 μm) over 545 s. Raw data is in lighter color (yellow is 0% Cl, light green is 1% Cl, teal is 5% Cl, and 10% Cl is dark green) with 100 s rolling average in darker color. Bar plots of fitted onset of discoloration of $\text{CsPb}(\text{I}_{0.80}\text{Br}_{0.20-x}\text{Cl}_x)_3$ of films held at (c) 100 °C, (d) 85 °C, and (e) 60 °C, black bar indicates respective standard deviation. For samples where no discoloration onset was observed, the onset of discoloration was conservatively estimated as the final test time. Bars encompassing such samples have the count of occurrences denoted by a number, accompanied by an asterisk, placed above them. A total of 2 samples per condition were observed for 100 °C and 85 °C temperatures, with 4 samples observed for 60 °C.

packages in Fig. S10.† As can be seen, all films photodarken with no clear correlation to Cl loading. While surface reactions affecting passivation cannot be ruled out as a plausible explanation, the diminishing PL appears consistent with previous reports that illumination introduces defects into a CsPbI_3 lattice.⁸⁴ In contrast with the PL intensity, the peak emission energy for single phase conditions remain stable (Fig. 5a), suggesting that the halide distribution does not change with time. The lack of change in emission energy for single phase film compositions further suggests that the laser induced defects are not strongly affected by halide heterogeneity, while the multiple phase 10% Cl shows indication of halide instability. Thus, it appears that increasing Cl content up to 5% halide fraction increases PL intensity in the inorganic perovskites with a modest blue-shift in emission that is stable against light-induced halide redistribution/segregation. The stability of the PL emission energy of the inorganic triple halide perovskites shown here indicates the ability to maintain the absorber's applicability to a targeted spectral design.

Lastly, it appears that the perovskite phase stability at elevated temperatures increases with uniform Cl incorporation, but is adversely affected by secondary phases. To understand

how Cl incorporation affects thermal stability, three sets of films were imaged over a 70 h period at 60 °C, 85 °C, and 100 °C (see ESI† for videos) to visualize color changes over time indicative of the time point at which the photoactive black phase (α , β or γ) begins to degrade (example onset fitting in Fig. S11†). As can be seen in Fig. 5c–e, at 60 °C, 85 °C, and 100 °C, Cl incorporation reproducibly enhances the phase stability of the films at low Cl loadings with the best thermal stability at 5% Cl, followed by a reduction in stability at higher loading. This reduction is likely explained by the initial presence of multiple phases in films with 10% Cl. At a lower temperature of 60 °C, Cl has a smaller effect on the photoactive phase thermal stability but many films did not degrade within the duration of the test. By the tolerance factor heuristic, Cl addition into the inorganic triple halide alloy should favor perovskite phase formation. Thus, it is expected that Cl incorporation should lower the temperature at which the black perovskite phase is thermodynamically stable, as appears to be the case from the 60 °C, 85 °C, and 100 °C data.

These photo- and thermal stability tests on bare films permit a direct determination of improvements in underlying phase stability in thin films as a function of composition of the perovskite. Unlike full devices, which include transport, contact and often passivation layers that can inhibit phase transformation or provide encapsulation,^{85,86} the tests shown here are on standalone perovskite films. Overall, the improvement of bare inorganic perovskite thin films thermal stability at elevated temperatures relevant to optoelectronic device operating conditions including terrestrial photovoltaics indicates Cl incorporation as an additional opportunity to overcome the metastability of perovskites.

4 Conclusion

Herein, we have explored Cl alloys of up to 10% Cl in ≈ 1.83 eV bandgap $\text{CsPb}(\text{I}_{0.80}\text{Br}_{0.20-x}\text{Cl}_x)_3$ films. Specifically, we have shown three distinct regimes of behavior dependent on Cl loading: (i) at low loadings of $\approx 1\%$ Cl most all Cl volatilizes during crystallization annealing, (ii) at moderate Cl loading of $\approx 5\%$ Cl, the Cl remaining after annealing incorporates uniformly into the lattice, and (iii) at higher Cl loading, most Cl precipitates out into a Cl-rich phase.

We find that alloying Cl up through moderate loading shrinks the perovskite lattice, blue-shifts its PL modestly, increases PL intensity by a factor of 5 \times , and significantly enhances black-phase thermal stability at 60–100 °C by up to 7 \times while maintaining relatively stable PL emission energy under laser illumination. In contrast at higher loadings, we find evidence of a second phase leading to a narrowed bandgap of the main I-rich perovskite and low thermal and photostability. These data indicate that incorporating Cl into a single-phase alloy presents an opportunity to enhance the thermal stability and optoelectronic properties of interest in triple-halide inorganic perovskites relative to Br/I inorganic perovskites. These findings ultimately suggest that replacing $\approx 5\%$ Br with Cl can result in distinct improvement in both thermal stability and



optoelectronic quality of the CsPbI₃ host crystal without significantly altering the bandgap.

Data availability

Data supporting the findings of this study are available from the corresponding author upon reasonable request.

Author contributions

D. N. C. led all experiments, data curation, formal analysis, and visualizations. C. J. D., Y. L., R. E. K., T. Z., Z. C., B. L., M. H. assisted with synchrotron measurements. E. O. assisted with sample preparations. D. P. F. came up with the experimental framework and led funding acquisition and supervised the research. D. N. C., S. P. D. wrote original draft, while the final review and editing of the manuscript saw contributions from all authors.

Conflicts of interest

There are no conflicts to declare.

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